DATA SHEET

PCD5091
DECT baseband controller

Objective specification
Supersedes data of 1996 Oct 30
File under Integrated Circuits, IC17

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Philips
Semiconductors

PHILIPS

CONTENTS

1 FEATURES

- 80C51 ports P0, P1, P2 and P3 available for interfacing to display, keyboard, I^2C-bus, interrupt sources and/or external memory. Integrated 64 kbyte ROM, 3 kbytes of data memory and 1 kbyte SDR-RAM. External program memory is addressable up to 128 kbytes
- +2.7 to +5 V port (P0 to P3) interface
- TDMA frame (de)multiplexing. Transmission or reception can be programmed for any slot
- Ciphering, scrambling, CRC checking/generation and protected B-fields
- Speech and data buffering space for six handsets
- Local call and B-field loop-back
- Two interrupt lines for BML and DSP to interrupt 80C51
- On-chip, three-channel time-multiplexed 8-bit Analog-to-Digital Converter (ADC) for RSSI measurement, one for battery voltage measurement and one channel available for other purposes
- On-chip 8-bit Digital-to-Analog Converter (DAC) for electronic potentiometer function
- Phase error measurement and phase error correction by hardware
- DACs and ADCs for dynamic earpiece and dynamic or electret microphone
- On-chip reference voltage
- On-chip supply for electret microphone
- Very low ohmic buzzer output
- Serial interface to external ADPCM CODEC (PCD5032) or 8 kHz u-law samples
- Speech switch for Digital Telephone Answering Machine (DTAM) connected to SPI interface
- IOM-2 interface (Siemens registered trademark)
- Serial interface to synthesizer for frequency programming
- Programmable polarity and timing of radio-control signals
- GMSK pulse shaper
- Easy interfacing with radio circuits, operating at other supply voltage (RF supply pin with level shifter for RF signals)
- On-chip comparator for use as data-slicer
- Low power oscillator with integrated frequency adjustment
- QFP100 and LQFP100 packages
- Power-on-reset
- Programmable power-down modes
- Low supply voltage (2.7 to 3.6 V)
- CMOS technology.

1.1 DSP software features

- ADPCM encoding and decoding complying with G.721
- Volume control
- Speech filters
- Programmable gain in speech paths
- Side tone and soft mute
- Two tone (DTMF) generators
- Automatic gain control
- Hands-free operation

For each DSP software version a separate manual is available in which detailed information is provided on how parameters must be set. For further information please contact Philips Semiconductors.

2 GENERAL DESCRIPTION

The PCD5091 is designed for GAP-compliant handsets with speaker-phone option. It has an embedded 80C51 microcontroller with twice the performance of the classic architecture, 64 kbytes of PROM program memory and 3 kbytes of data memory on-chip. In addition there is 1 kbyte of on-chip data memory that is shared with on-chip Burst Mode Logic (BML) and DSP, the System Data RAM (SDR).

3 ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PCD5091H	QFP100	plastic quad flat package; 100 leads (lead length 1.95 mm); body $14 \times 20 \times 2.8$ mm	SOT317-2
PCD5091HZ	LQFP100	plastic low profile quad flat package; 100 leads; body $14 \times 14 \times 1.4$ mm	SOT407-1

4 BLOCK DIAGRAM

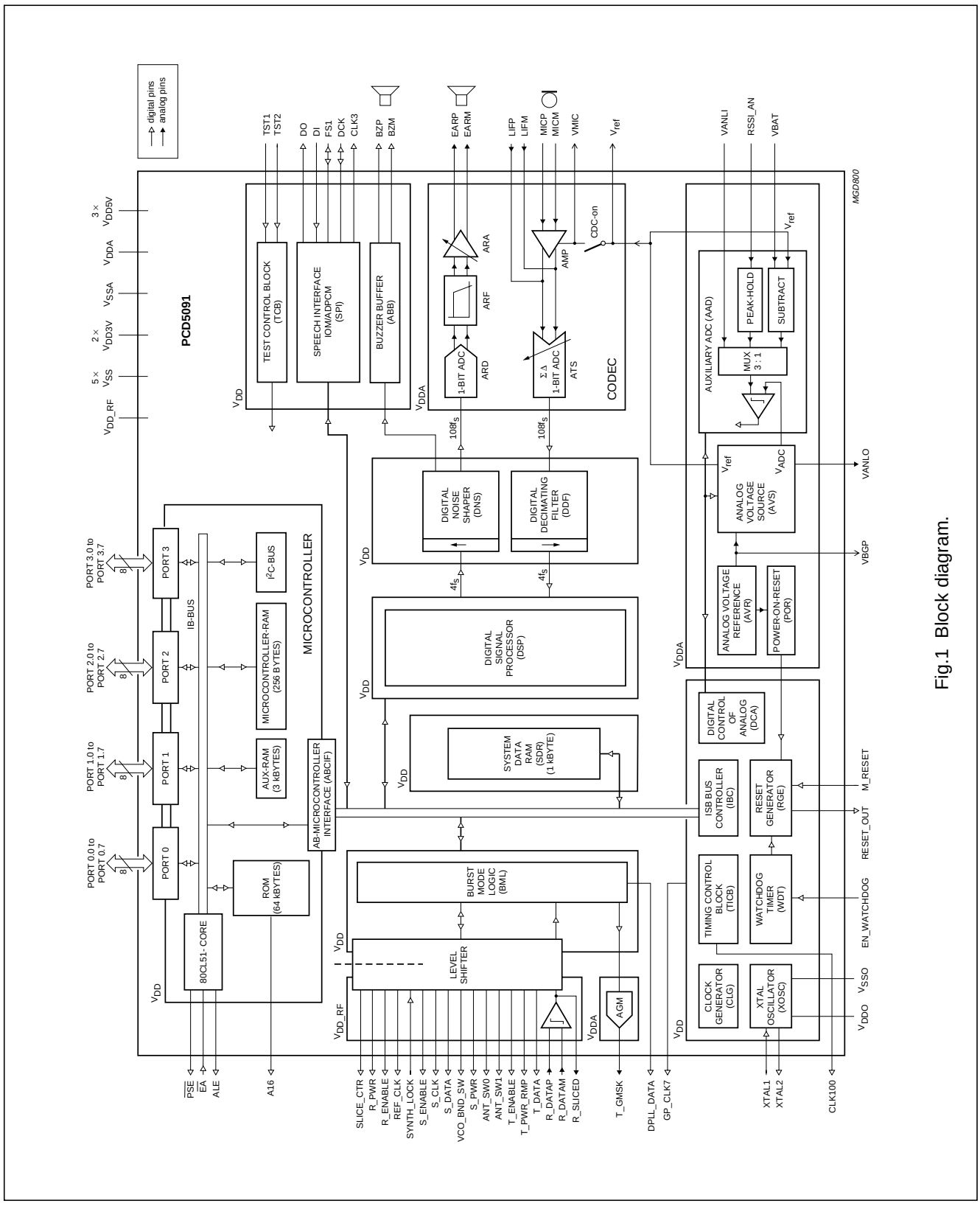


Fig.1 Block diagram.

5 PINNING INFORMATION

5.1 Pinning

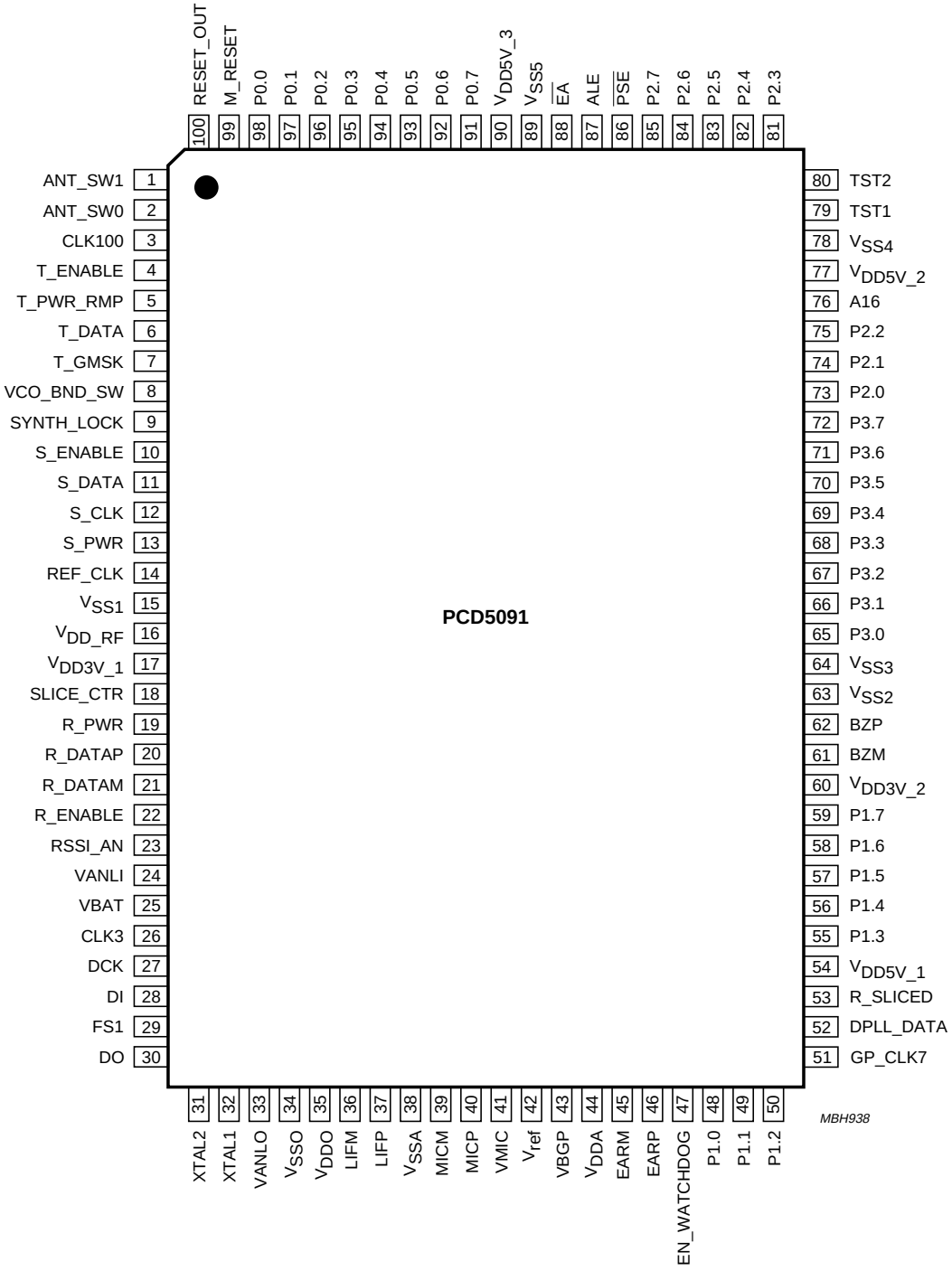


Fig.2 Pin configuration (QFP100).

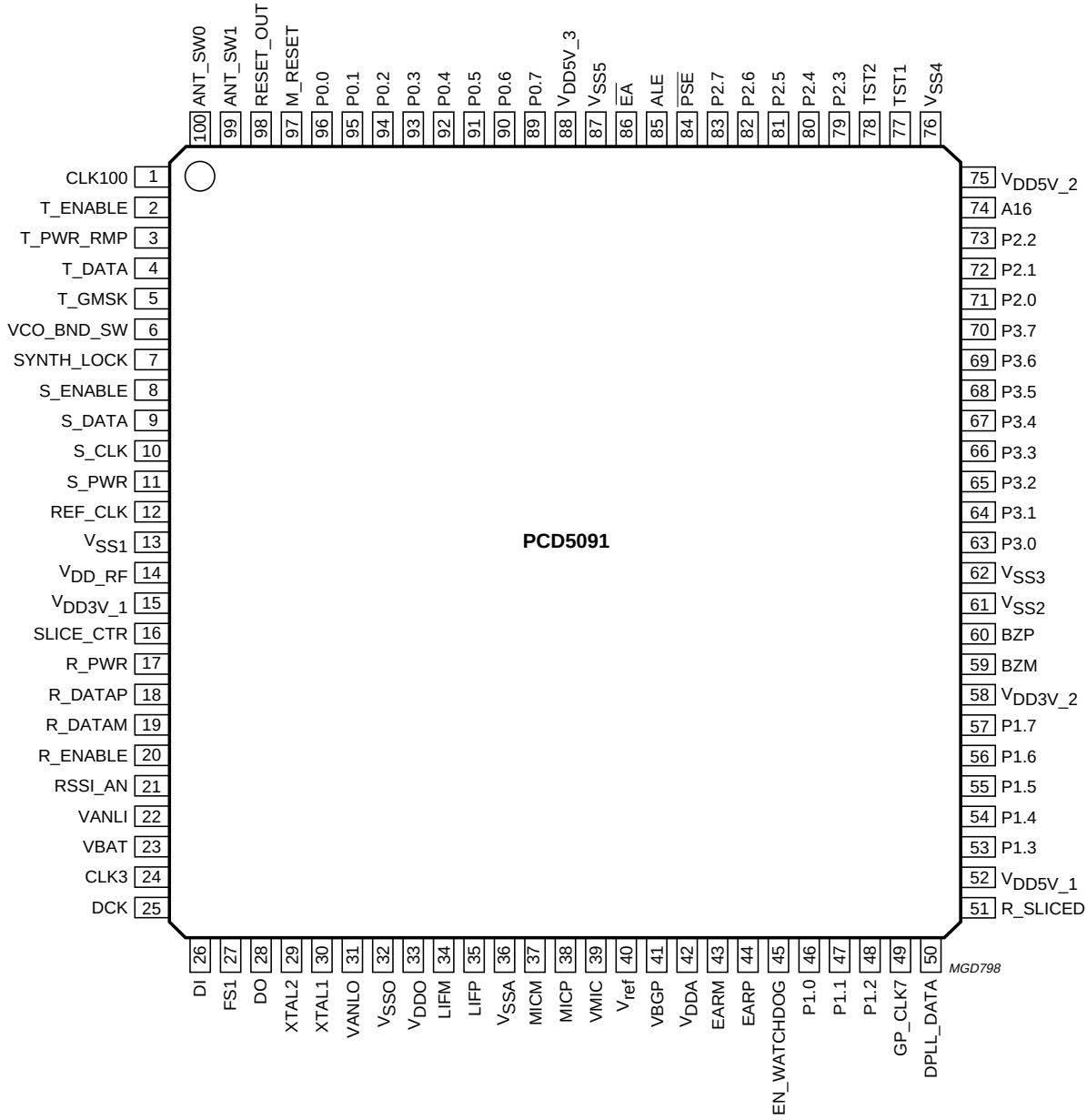


Fig.3 Pin configuration (LQFP100).

5.2 Pin description

Table 1 QFP100 and LQFP100 packages

SYMBOL	PIN		I/O	STATE AFTER RESET	PIN TYPE	PIN DESCRIPTION
	QFP100	LQFP100				
ANT_SW1	1	99	O	H	ISP2DRF3	antenna switch 1 output
ANT_SW0	2	100	O	H	ISP2DRF3	antenna switch 0 output
CLK100	3	1	O	H	ISP2DPES	100 Hz signal related to DECT frame timing output
T_ENABLE	4	2	O	H	ISP2DRF3	enable transmitter output
T_PWR_RMP	5	3	O	L	ISP2DRF3	switch transmitter power output
T_DATA	6	4	O	off	ISF2DRF3	unmodulated transmitter data output
T_GMSK	7	5	O	L	ANAIOD1	GMSK modulated transmitter data output
VCO_BND_SW	8	6	O	L	ISP2DRF3	VCO band switch output
SYNTH_LOCK	9	7	I	–	DIPP0RF3	synthesizer lock input
S_ENABLE	10	8	O	L	ISP2DRF3	synthesizer enable output
S_DATA	11	9	O	L	ISP2DRF3	serial synthesizer data output
S_CLK	12	10	O	L	ISP2DRF3	clock for serial synthesizer interface output
S_PWR	13	11	O	H	ISP2DRF3	switch synthesizer power output
REF_CLK	14	12	O	running	ISP4DRF3	13.824 MHz reference clock for synthesizer output
V_{SS1}	15	13	–	–	supply	negative supply voltage 1
V_{DD_RF}	16	14	–	–	supply	positive supply voltage for RF interface level shifters
V_{DD3V_1}	17	15	–	–	supply	positive supply voltage 1 (+3 V)
SLICE_CTR	18	16	O	L	ISP2DRF3	switch slicer time constant output
R_PWR	19	17	O	H	ISP2DRF3	switch receiver power output
R_DATAP	20	18	I	–	ANAIOD2	positive input for receiver data
R_DATAM	21	19	I	–	ANAIOD2	negative input for receiver data
R_ENABLE	22	20	O	H	ISP2DRF3	enable receiver output
RSSI_AN	23	21	I	–	ANAIOD1	analog input for RSSI measurement
VANLI	24	22	I	–	ANAIOD1	analog input to ADC
VBAT	25	23	I	–	ANAIOD1	analog input for battery voltage measurement
CLK3	26	24	O	L	ISP2DPES	3.456 MHz clock output for external ADPCM codec

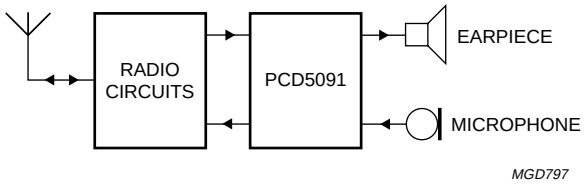
SYMBOL	PIN		I/O	STATE AFTER RESET	PIN TYPE	PIN DESCRIPTION
	QFP100	LQFP100				
DCK	27	25	I/O	input	ISF2DPES ISF2UPES	ADPCM output or IOM data clock input/output (ISF2UPES in PCD5090/xxx, PCA5097/xxx)
DI	28	26	I	–	DIPP0PES	ADPCM or IOM data input
FS1	29	27	I/O	input	ISF2DPES ISF2UPES	8 kHz framing input/output (ISF2UPES in PCD5090/xxx, PCA5097/xxx)
DO	30	28	O	off	ISI8DPES	ADPCM or IOM data output
XTAL2	31	29	O	running	ANAIOD1	crystal oscillator output
XTAL1	32	30	I	–	ANAIOD1	crystal oscillator input
VANLO	33	31	O	1.0 V	ANAIOD1	analog output from D/A converter
V_{SSO}	34	32	–	–	supply	negative supply voltage for the oscillator
V_{DDO}	35	33	–	–	supply	positive supply voltage for the oscillator
LIFM	36	34	I	0.7 V	ANAIOD1	negative input from line interface
LIFP	37	35	I	0.7 V	ANAIOD1	positive input from line interface
V_{SSA}	38	36	–	–	supply	negative supply voltage for analog circuits
MICM	39	37	I	0.7 V	ANAIOR1	negative input from microphone
MICP	40	38	I	0.7 V	ANAIOR1	positive input from microphone
VMIC	41	39	O	off	ANAIOD1	positive microphone supply voltage (+2 V)
V_{ref}	42	40	O	2.0 V	ANAIOD1	reference voltage (+2 V)
VBGP	43	41	O	1.25 V	ANAIOR1	bandgap output voltage (+1.25 V)
V_{DDA}	44	42	–	–	supply	positive supply voltage for analog circuits
EARM	45	43	O	1.4 V	ANAIOD1	negative output to earpiece
EARP	46	44	O	1.4 V	ANAIOD1	positive output to earpiece
EN_WATCHDOG	47	45	I	–	DIUP0PES	watchdog enable input
P1.0	48	46	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P1.1	49	47	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P1.2	50	48	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
GP_CLK7	51	49	O	L	ISP2DPES	general purpose 6.912 MHz output
DPLL_DATA	52	50	O	L	ISP2DPES	data after clock recovery network
R_SLICED	53	51	O	L	ISP2DPES	R_DATA comparator output
V_{DD5V_1}	54	52	–	–	supply	positive supply voltage 1 for the +5 V interface
P1.3	55	53	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P1.4	56	54	I/O	H	ISQ2CPES	bidirectional 80C51 port pin

SYMBOL	PIN		I/O	STATE AFTER RESET	PIN TYPE	PIN DESCRIPTION
	QFP100	LQFP100				
P1.5	57	55	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P1.6	58	56	I/O	off	ISI8DPES	bidirectional 80C51 port pin
P1.7	59	57	I/O	off	ISI8DPES	bidirectional 80C51 port pin
V_{DD3V_2}	60	58	–	–	supply	positive supply voltage 2 (+3 V)
BZM	61	59	O	L	ANAIOD2	negative buzzer output
BZP	62	60	O	L	ANAIOD2	positive buzzer output
V_{SS2}	63	61	–	–	supply	negative supply voltage 2
V_{SS3}	64	62	–	–	supply	negative supply voltage 3
P3.0	65	63	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.1	66	64	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.2	67	65	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.3	68	66	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.4	69	67	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.5	70	68	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.6	71	69	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P3.7	72	70	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.0	73	71	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.1	74	72	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.2	75	73	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
A16	76	74	O	L	ISP4DPES	address bit 16 for 128 kbytes external program memory
V_{DD5V_2}	77	75	–	–	supply	positive supply voltage 2 for the +5 V interface
V_{SS4}	78	76	–	–	supply	negative supply voltage 4
TST1	79	77	I	–	DIDP0PES	test input 1
TST2	80	78	I	–	DIDP0PES	test input 2
P2.3	81	79	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.4	82	80	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.5	83	81	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.6	84	82	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
P2.7	85	83	I/O	H	ISQ2CPES	bidirectional 80C51 port pin
$\overline{PSE}$	86	84	O	H	ISQ2CPES	program store enable (80C51); active LOW
ALE	87	85	O	H	ISQ4CPES	address latch enable (80C51)

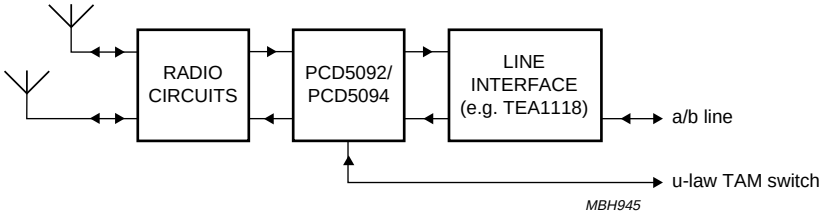
SYMBOL	PIN		I/O	STATE AFTER RESET	PIN TYPE	PIN DESCRIPTION
	QFP100	LQFP100				
$\overline{EA}$	88	86	I	–	ISF2DPES	external access enable (80C51); active LOW
V_{SS5}	89	87	–	–	supply	negative supply voltage 5
V_{DD5V_3}	90	88	–	–	supply	positive supply voltage 3 for the +5 V interface
P0.7	91	89	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.6	92	90	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.5	93	91	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.4	94	92	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.3	95	93	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.2	96	94	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.1	97	95	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
P0.0	98	96	I/O	off H	ISP2DPES ISQ2CPES	bidirectional 80C51 port pin (ISQ2CPES in PCD5090/xxx, PCA5097/xxx)
M_RESET	99	97	I	–	DIDP0PES	master reset input (Schmitt trigger)
RESET_OUT	100	98	O	H	ISF2DPES	reset output

6 FUNCTIONAL DESCRIPTION

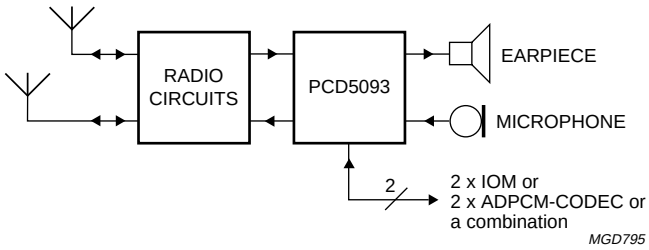
The PCD509x is a family of single-chip controllers, designed for use in Digital Enhanced Cordless Telecommunications systems (DECT). The family is designed for minimum component-count and minimum power consumption. All controllers include an embedded 80C51 microcontroller with on-chip memory and I^2C-bus. The Philips DECT RF interface is implemented. The Burst Mode Logic (BML) performs the time-critical MAC layer functions for applications in DECT handsets and base stations. The ADPCM transcoding is in compliance with the CCITT recommendation G.721 and includes receive and transmit filters.



a. Handset.



b. Base with analog interface and echo cancellation; up to 6 portables can be handled.

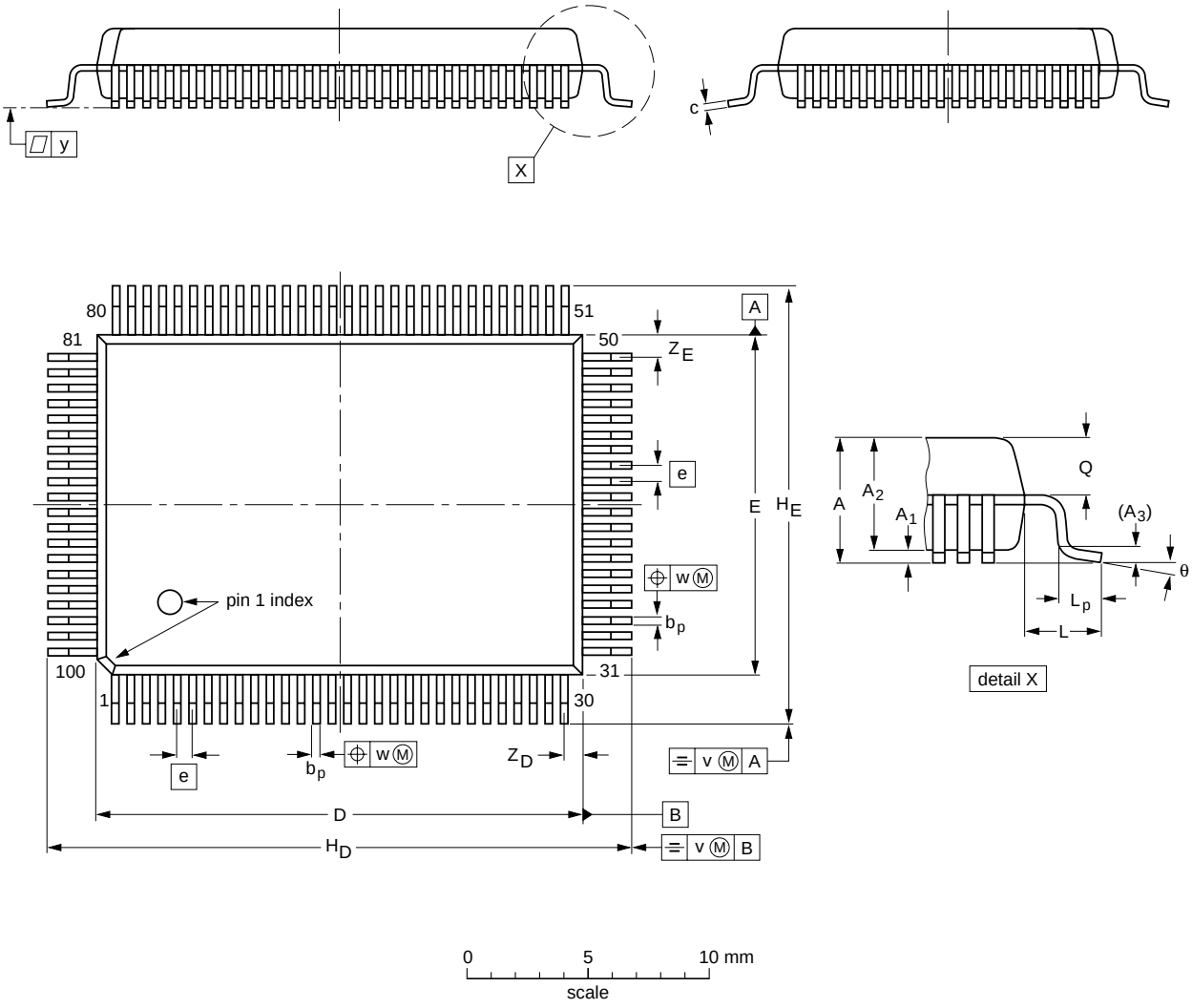


c. Base with digital interface and analog handset connected; up to 6 portables can be handled.

Fig.4 Block diagrams of DECT systems with PCX509x.

7 PACKAGE OUTLINE

QFP100: plastic quad flat package; 100 leads (lead length 1.95 mm); body 14 x 20 x 2.8 mm **SOT317-2**



DIMENSIONS (mm are the original dimensions)

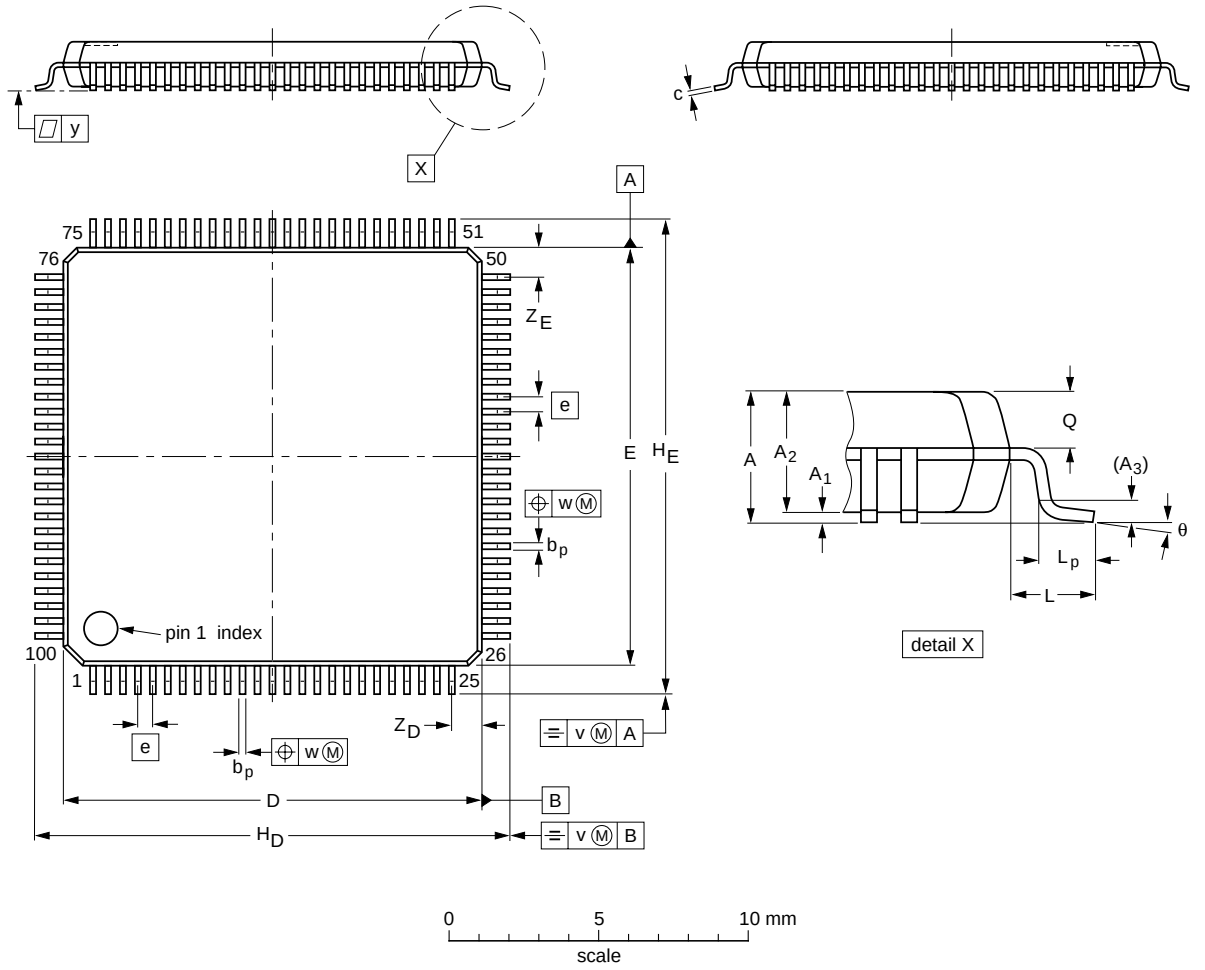
UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_D	H_E	L	L_p	Q	v	w	y	$Z_D^{(1)}$	$Z_E^{(1)}$	θ
mm	3.20	0.25 0.05	2.90 2.65	0.25	0.40 0.25	0.25 0.14	20.1 19.9	14.1 13.9	0.65	24.2 23.6	18.2 17.6	1.95	1.0 0.6	1.4 1.2	0.2	0.15	0.1	0.8 0.4	1.0 0.6	7^o 0^o

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT317-2						~~92-11-17~~ 95-02-04

LQFP100: plastic low profile quad flat package; 100 leads; body 14 x 14 x 1.4 mm **SOT407-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_D	H_E	L	L_p	Q	v	w	y	$Z_D^{(1)}$	$Z_E^{(1)}$	θ
mm	1.6	0.20 0.05	1.5 1.3	0.25	0.28 0.16	0.18 0.12	14.1 13.9	14.1 13.9	0.5	16.25 15.75	16.25 15.75	1.0	0.75 0.45	0.70 0.57	0.2	0.12	0.1	1.15 0.85	1.15 0.85	7^o 0^o

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT407-1						95-12-19

8 SOLDERING

8.1 Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

8.2 Reflow soldering

Reflow soldering techniques are suitable for all LQFP and QFP packages.

The choice of heating method may be influenced by larger plastic QFP packages (44 leads, or more). If infrared or vapour phase heating is used and the large packages are not absolutely dry (less than 0.1% moisture content by weight), vaporization of the small amount of moisture in them can cause cracking of the plastic body. For more information, refer to the Drypack chapter in our *"Quality Reference Handbook"* (order code 9397 750 00192).

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

8.3 Wave soldering

Wave soldering is **not** recommended for LQFP or QFP packages. This is because of the likelihood of solder bridging due to closely-spaced leads and the possibility of incomplete solder penetration in multi-lead devices.

If wave soldering cannot be avoided, the following conditions must be observed:

- **A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.**
- **The footprint must be at an angle of 45° to the board direction and must incorporate solder thieves downstream and at the side corners.**

Even with these conditions:

- **Do not consider wave soldering LQFP packages LQFP48 (SOT313-2), LQFP64 (SOT314-2) or LQFP80 (SOT315-1).**
- **Do not consider wave soldering QFP packages QFP52 (SOT379-1), QFP100 (SOT317-1), QFP100 (SOT317-2), QFP100 (SOT382-1) or QFP160 (SOT322-1).**

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

8.4 Repairing soldered joints

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

9 DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Short-form specification	The data in this specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

10 LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

11 PURCHASE OF PHILIPS I²C COMPONENTS

Purchase of Philips I²C components conveys a license under the Philips' I²C patent to use the components in the I²C system provided the system conforms to the I²C specification defined by Philips. This specification can be ordered using the code 9398 393 40011.

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